

TRANSISTOR MODULE

SQD400AA120

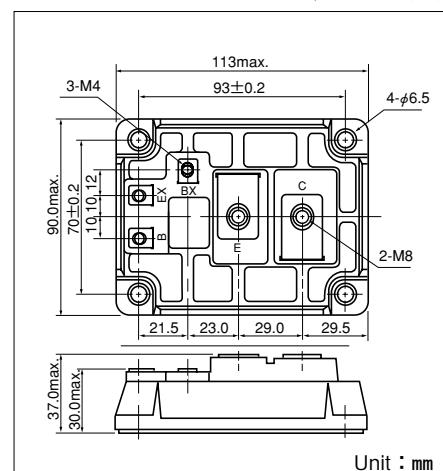
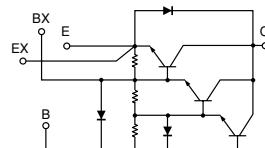
UL:E76102(M)

SQD400AA120 is a Darlington power transistor module with a high speed, high power Darlington transistor. The transistor has a reverse paralleled fast recovery diode. The mounting base of the module is electrically isolated from Semiconductor elements for simple heatsink construction.

- $I_C = 400A$, $V_{CEX} = 1200V$
- Low saturation voltage for higher efficiency
- High DC current gain.
- Isolated mounting base

(Applications)

Motor Control (VVVF), AC/DC Servo, UPS,
Switching Power Supply, Ultrasonic Application



■ Maximum Ratings

($T_j = 25^\circ C$ unless otherwise specified)

Symbol	Item	Conditions	Ratings	Unit
			SQD400AA120	
V_{CBO}	Collector-Base Voltage		1200	V
V_{CEX}	Collector-Emitter Voltage	$V_{BE} = -2V$	1200	V
$V_{CEX(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C = 80A$, $I_B = -18A$	1200	V
V_{EBO}	Emitter-Base Voltage		10	V
I_C	Collector Current		400	A
$-I_C$	Reverse Collector Current		400	A
I_B	Base Current		20	A
P_T	Total power dissipation	$T_c = 25^\circ C$	3120	W
T_j	Junction Temperature		-40 to +150	°C
T_{stg}	Storage Temperature		-40 to +125	°C
V_{iso}	Isolation Voltage	A.C. 1minute	2500	V
	Mounting Torque	Mouting (M6)	Recommended Value 2.5-3.9 (25-40)	N·m (kgf·cm)
		Terminal (M8)	Recommended Value 8.8-10 (90-105)	
		Terminal (M4)	Recommended Value 1.0-1.4 (10-14)	
Mass		Typical Value	670	g

■ Electrical Characteristics

Symbol	Item	Conditions	Ratings		Unit
			Min.	Max	
I_{CBO}	Collector Cut-off Current	$V_{CB} = 1200V$		5.00	mA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 10V$		1000	mA
h_{FE}	DC Current Gain	$I_C = 400A$, $V_{CE} = 2.8V$	75		
		$I_C = 400A$, $V_{CE} = 5V$	100		
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 400A$, $I_B = 8A$		3.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 400A$, $I_B = 8A$		3.5	V
t_{on}	Switching Time	On Time		3.0	μs
t_s		Storage Time		17.0	
t_f		Fall Time		3.0	
V_{ECO}	Collector-Emitter Reverse Voltage	$I_C = -400A$		1.8	V
$R_{th(j-c)}$	Thermal Impedance (junction to case)	Transistor part		0.04	$^\circ C/W$
		Diode part		0.16	

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